

ELECTRICAL ENGINEERING

CONVENTIONAL Practice Sets

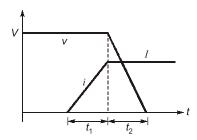
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Power Semi-conductor Diode and Transistor

Q.1 The voltage across and current through a power semiconductor device switching transients are shown in the figure. Deduce the expression for the energy lost in the ON/OFF transition in terms of V, I, t and t₂.



Solution:

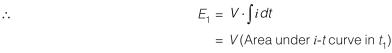
During t_1 interval voltage is constant (V), while current starts increasing. Thereafter, in t_2 interval voltage starts decreasing and becomes zero and current becomes constant (I), so the transition is turn on.

During t_1 interval:

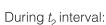
Power loss =
$$vi$$

Energy loss,
$$E_1 = \int vi dt [= E_1(Say)]$$

:: v is constant in this interval,







Power loss =
$$vi$$

Energy loss,
$$E_2 = \int vi dt$$

:: i is constant in the interval (=I)

$$E_2 = I \cdot \int v \, dt$$

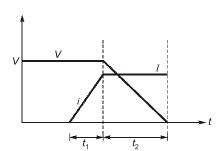
$$= I \text{ (Area under } v\text{-}t \text{ curve in } t_2 \text{)}$$

or
$$E_2 = I\left(\frac{1}{2}Vt\right) = \frac{1}{2}VIt_2$$

Therefore, total energy lost during ON transition,

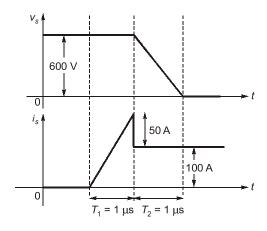
$$E_{\text{lost}} = E_1 + E_2 = \frac{1}{2}VIt_1 + \frac{1}{2}VIt_2$$

or,
$$E_{\text{lost}} = \frac{1}{2} VI(t_1 + t_2)$$





Q2 If the voltage (V_s) across and current (i_s) through a power semiconductor switch during turn-on process are shown in the figure below, then calculate the energy dissipated during the turn-on process.



Solution:

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We know that, Energy = $\int_{0}^{t} Vi \, dt$

Here, Energy = $E_I + E_{II} + E_{III}$

$$= V \cdot 0 + \int_{t_1}^{t_2} V \cdot i_s \, dt + \int_{t_2}^{t_3} V_s \cdot I_2 \, dt$$

$$= 0 + V \int_{0}^{T_1} i_s \, dt + I_2 \int_{0}^{T_2} V_s \, dt$$

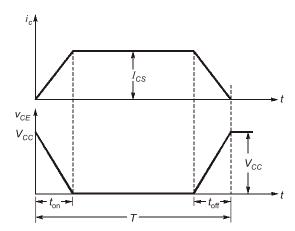
$$= V \left[\frac{1}{2} I_1 T_1 \right] + I_2 \left[\frac{1}{2} V T_2 \right]$$

$$= 600 \left[\frac{150}{2} \times 1 \times 10^{-6} \right] + 100 \left[\frac{600}{2} \times 1 \times 10^{-6} \right]$$

$$= 75000 \times 10^{-6} \text{ J}$$

Energy =
$$75 \, \text{mJ}$$

Find the energy loss during switch-on and off intervals of a power transistor with switching characteristics as shown in the figure. Where $I_{CS} = 80 \text{ A}$, $V_{CC} = 220 \text{ V}$, $t_{on} = 1.5 \text{ ms}$ and $t_{off} = 4 \text{ ms}$. Also determine the average power loss in the transistor if switching frequency is 2 kHz.







Solution:

From the switching characteristics given in the figure above.

Energy loss during trun-on
$$(E_{\text{loss (on)}}) = \int\limits_0^{t_{on}} i_c \cdot v_{CE} \, dt$$

$$= \int\limits_0^{t_{on}} \left[\frac{I_{CS}}{t_{on}} \right] t \cdot \left(V_{CC} - \frac{V_{CC}}{t_{on}} t \right) dt$$

$$= \int\limits_0^{t_{on}} \frac{I_{CS} V_{CC}}{t_{on}} \cdot t \, dt - \int\limits_0^{t_{on}} \frac{I_{CS} V_{CC}}{t_{on}^2} \cdot t^2 \, dt$$

$$= \frac{I_{CS} V_{CC}}{t_{on}} \cdot \frac{t_{on}^2}{2} - \frac{I_{CS} V_{CC}}{t_{on}^2} \cdot \frac{t_{on}^3}{3} = \frac{I_{CS} V_{CC}}{6} \cdot t_{on}$$

$$\therefore \qquad E_{\text{loss(on)}} = \frac{80 \times 220}{6} \times 0.15 \times 10^{-3} \text{ Watt-sec.}$$

$$E_{\text{loss(off)}} = \frac{I_{CS} V_{CC}}{6} \cdot t_{off}$$
or
$$E_{\text{loss(off)}} = \frac{I_{CS} V_{CC}}{6} \times 0.4 \times 10^{-3} \text{ Watt-sec.}$$

$$\therefore \qquad E_{\text{loss(off)}} = \frac{80 \times 220}{6} \times 0.4 \times 10^{-3} \text{ Watt-sec.}$$

$$Average power loss in the power transistor for switching frequency of 2 kHz}$$

$$= (\text{Energy loss in ON and OFF switching}) \times \text{Switching frequency}$$

$$= \frac{I_{CS} V_{CC}}{6} (t_{on} + t_{off}) \times f$$
$$= (0.44 + 1.17) \times 2 \times 10^3 = 3.22 \text{ kW}$$

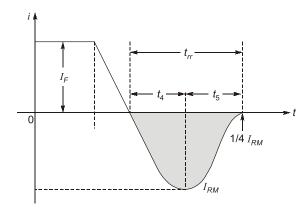
Q4 For a power diode, the reverse recovery time is 3.9 μs and the rate of diode-current decay is 50 A/μs. For a softness factor of 0.3, calculate the peak inverse current and storage charge.

Solution:

Given, Reverse recovery time $(t_{rr}) = 3.9 \,\mu s$

Softness factor
$$\left(\frac{t_5}{t_4}\right) = 0.3$$

$$\vdots \qquad \qquad t_5 = 0.3 \ t_4 \\ t_{rr} = t_4 + t_5 = 3.9 \ \mu s$$
or,
$$1.3 \ t_4 = 3.9 \ \mu s$$
or,
$$t_4 = 3 \ \mu s$$
Given,
$$\frac{di}{dt} = 50 \ \text{A/}\mu s$$



The peak inverse current $I_{\it RM}$ can be expressed as:

$$I_{RM} = t_4 \frac{di}{dt} = 3 \times 50 \text{ Amp.}$$

 $I_{RM} = 150 \text{ Amp.}$



Assuming reverse recovery characteristic to be triangular,

Storage charge (
$$Q_R$$
) = $\frac{1}{2}I_{RM} \cdot t_{rr} = \frac{1}{2} \times 150 \times 3.9 \,\mu C$
 Q_R = 292.5 μ C
 I_{RM} = 150 A and Q_R = 292.5 μ C

- Q.5 For the circuit shown in figure below, determine:
 - (a) Power loss in the on-state
 - (b) Power loss during the turn-on interval.

MOSFET parameters are: $t_r = 2$ ms, $R_{DS(on)} = 0.2 \Omega$, duty cycle (D) = 0.7 and f = 30 kHz.

Solution:

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When MOSFET is on:

Drain current,

$$I_D = \frac{V_{DS}}{R_L + R_{DS(on)}}$$

= $\frac{100}{12 + 0.2} = 8.197 \text{ A}$ $V_{DS} = 100 \text{ V} \frac{+}{-}$



Switching period,

$$T = \frac{1}{f} = \frac{1}{30 \times 10^3} = 33.333 \,\mu\text{sec}$$

Duty cycle (D) =
$$\frac{t_{on}}{T}$$

.. on time is given by,

$$t_{\text{on}} = D \cdot T = 0.7 \times 33.333 \times 10^{-6}$$

= 23.3331 \mus

(a) Energy loss during on state,

$$E_{\text{on}} = I_D^2 R_{DS(\text{on})} \cdot t_{\text{on}}$$

= $(8.197)^2 \times 0.2 \times (23.3331 \times 10^{-6})$
= $313.554 \,\mu\text{J}$

Now, power loss during on state,

$$P_{\text{on}} = E_{\text{on}} \cdot f$$

= 313.554 × 10⁻⁶ × 30 × 10³
= 9.4066 W

(b) Energy loss during the turn-on [assuming triangular switching on characteristic]

$$E_{\text{turn-on}} = \frac{V_{DS} \cdot I_D \cdot t_r}{6} = \frac{100 \times 8.197}{6} \times 2 \times 10^{-6}$$
$$= 273.233 \,\mu\text{J}$$

Power loss during turn-on,

$$P_{\text{turn-on}} = E_{\text{turn-on}} \cdot f = 273.233 \times 10^{-6} \times 30 \times 10^{3}$$

= 8.197 W